

Low-Voltage, Low R_{ON}, Dual DPDT Analog Switch

DESCRIPTION

The DG2015 is a dual double-pole/double-throw monolithic CMOS analog switch designed for high performance switching of analog signals. Combining low power, high speed, low on-resistance and small physical size, the DG2015 is ideal for portable and battery powered applications requiring high performance and efficient use of board space.

The DG2015 is built on Vishay Siliconix's low voltage JI2 process. An epitaxial layer prevents latchup. Break-beforemake is guaranteed.

The switch conducts equally well in both directions when on, and blocks up to the power supply level when off.

FEATURES

- Halogen-free according to IEC 61249-2-21 Definition
- Low Voltage Operation (2.7 V to 3.3 V)
- Low On-Resistance R_{ON} : 0.85 Ω
- 3 dB Loss at 100 MHz
- Fast Switching: t_{ON} = 40 ns t_{OFF} = 35 ns
 - QFN-16 Package
- Compliant to RoHS Directive 2002/95/EC •

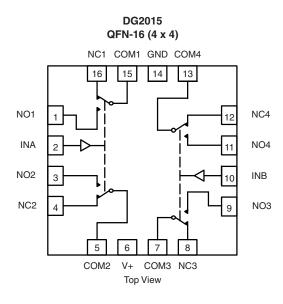
BENEFITS

- **Reduced Power Consumption**
- **High Accuracy**
- **Reduced Board Space**
- **Reduce Board Space** •
- TTL/1.8 V Logic Compatible

APPLICATIONS

- Cellular Phones
- Speaker Headset Switching
- Audio and Video Signal Routing
- PCMCIA Cards
- **Battery Operated Systems**

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



TRUTH TABLE						
Logic	NC1, 2, 3 and 4	NO1, 2, 3 and 4				
0	ON	OFF				
1	OFF	ON				

ORDERING INFORMATION					
Temp Range	Package	Part Number			
- 40 °C to 85 °C	16-pin QFN (4 mm x 4 mm)	DG2015DN-T1-E4			

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RoHS COMPLIANT HALOGEN FREE



Parameter	Limit	Unit		
Reference V+ to GND	- 0.3 to + 6	N/		
IN, COM, NC, NO ^a	- 0.3 to (V+ + 0.3)	V		
Current (Any terminal except NO, NC or C	30			
Continuous Current (NO, NC, or COM)	± 150	mA		
Peak Current (Pulsed at 1 ms, 10 % duty	± 200			
Storage Temperature (D Suffix)	- 65 to 150			
Package Solder Reflow Conditions ^d	16-pin QFN (4 mm x 4 mm)	240	- °C	
Power Dissipation (Packages) ^b QFN-16 ^c		1880	mW	

Notes:

a. Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings. b. All leads welded or soldered to PC Board.

c. Derate 23.5 mW/°C above 70 °C.

d. Manual soldering with iron is not recommended for leadless components. The QFN is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper lip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

SPECIFICATIONS (/+=3V)						
		Test Conditions Otherwise Unless Specified		Limits - 40 °C to 85 °C			Unit
Parameter	Symbol	V+ = 3 V, \pm 10 %, V _{IN} = 0.4 V or 2 V ^e	Temp. ^a	Min. ^b	Typ. ^c	Max. ^b	onic
Analog Switch	•	•			•		
Analog Signal Range ^d	V _{NO} , V _{NC} V _{COM}		Full	0		V+	V
On-Resistance	R _{ON}	V+ = 2.7 V, V _{COM} = 0.2 V/1.5 V, I _{NO} , I _{NC} = 100 mA	Room Full		0.85	1.6 1.7	
R _{ON} Flatness R _{ON} Flatness		V+ = 2.7 V, V _{COM} = 0 V to V+, I _{NO} , I _{NC} = 100 mA	Room		0.16		Ω
R _{ON} Match	ΔR_{ON}		Room		0.15		
Switch Off	I _{NO(off)} I _{NC(off)}	V+ = 3.3 V V _{NO} , V _{NC} = 1 V/3 V, V _{COM} = 3 V/1 V		- 1 - 10		1 10	nA
Leakage Current	I _{COM(off)}			- 1 - 10		1 10	
Channel-On Leakage Current	I _{COM(on)}	$V_{+} = 3.3 V, V_{NO}, V_{NC} = V_{COM} = 1 V/3 V$	Room Full	- 1 - 10		1 10	
Digital Control	•	•			•		
Input High Voltage	V _{INH}		Full	2			v
Input Low Voltage	V _{INL}		Full			0.4	v
Input Capacitance	C _{in}		Full		4		pF
Input Current	$I_{\rm INL}$ or $I_{\rm INH}$	V _{IN} = 0 V or V+	Full	- 1		1	μA
Dynamic Characteristics							
Turn-On Time	t _{ON}		Room Full		40	65 67	
Turn-Off Time	t _{OFF}	$V_{NO} \text{ or } V_{NC}$ = 2 V, R_L = 300 Ω , C_L = 35 pF	Room Full		35	60 62	ns
Break-Before-Make Time	t _d		Full	1	3		
Charge Injection ^d	Q _{INJ}	C_L = 1 nF, V_{GEN} = 0 V, R_{GEN} = 0 Ω			7		рС
Off-Isolation ^d	OIRR	$R_1 = 50 \Omega, C_1 = 5 pF, f = 1 MHz$			- 67		٩D
Crosstalk ^d	X _{TALK}	$1 - 1 = 30 \text{ sz}, 0 = 3 \text{ pr}, 1 = 1 \text{ M} \square Z$	Room		- 70		dB
N _O , N _C Off Capacitance ^d	C _{NO(off)}		Room		63		
	C _{NC(off)}	V _{IN} = 0 V or V+, f = 1 MHz	Room		67		pF
Channel-On Capacitance ^d	C _{NO(on)}		Room		200		Ч
Ghannel-On Gapachance	C _{NC(on}		Room		196		

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SPECIFICATIONS $(V + = 3 V)$							
		Test Conditions Otherwise Unless Specified		Limits - 40 °C to 85 °C		Unit	
Parameter	Symbol	V+ = 3 V, \pm 10 %, V _{IN} = 0.4 V or 2 V ^e	Temp. ^a	Min. ^b	Typ. ^c	Max. ^b	
Power Supply							
Power Supply Range	V+			2.7		3.3	V
Power Supply Current	l+	$V_{IN} = 0 V \text{ or } V+$	Full			1	μA
Power Consumption	P _C	v _{IN} = 0 v 01 v+	Full			3.3	μW

Notes:

a. Room = 25 °C, full = as determined by the operating suffix.

b. Typical values are for design aid only, not guaranteed nor subject to production testing.

c. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.

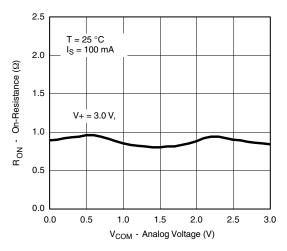
d. Guarantee by design, nor subjected to production test.

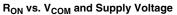
e. V_{IN} = input voltage to perform proper function.

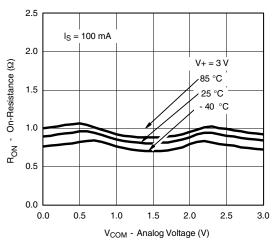
f. Guaranteed by 5 V leakage testing, not production tested.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

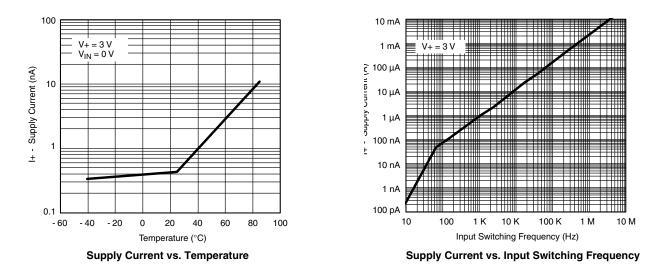
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)







R_{ON} vs. Analog Voltage and Temperature



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DG2015



I_{COM(off)}

INO(off), IINC(off)

2.5

3.0

2.0

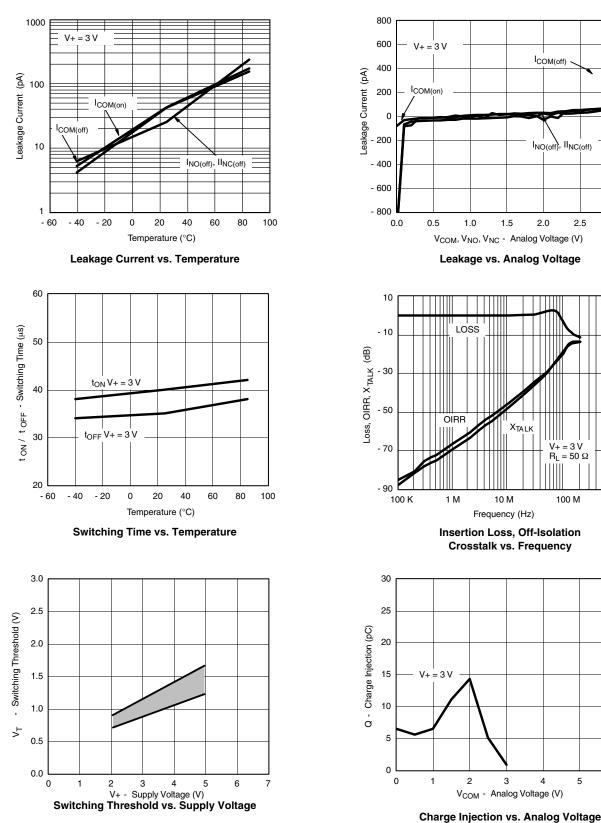
 $\begin{array}{l} \mathsf{V+}=3\;\mathsf{V}\\ \mathsf{R}_{\mathsf{L}}=50\;\Omega \end{array}$

100 M

1 G

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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



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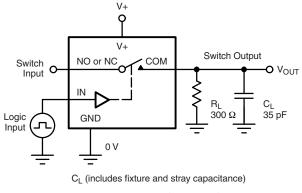
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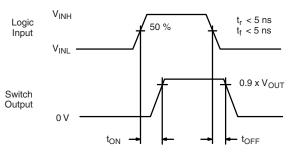


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TEST CIRCUITS



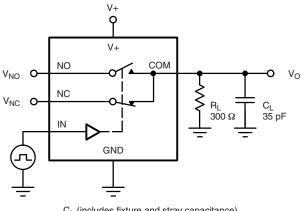




Logic "1" = Switch On Logic input waveforms inverted for switches that have the opposite logic sense.



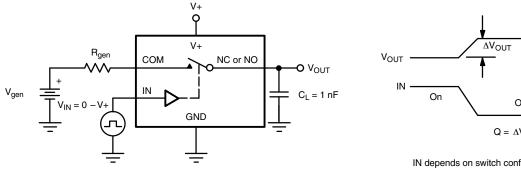
Logic

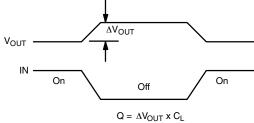


VINH $t_r < 5 ns$ Input $t_f < 5 ns$ VINL $V_{NC} = V_{NO}$ Vo 90 % Switch 0 V Output tD

C_L (includes fixture and stray capacitance)

Figure 2. Break-Before-Make Interval





IN depends on switch configuration: input polarity determined by sense of switch.

Figure 3. Charge Injection

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TEST CIRCUITS

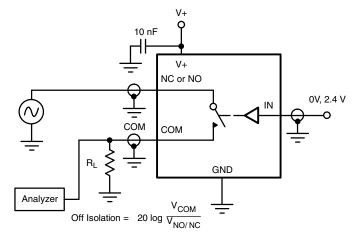


Figure 4. Off-Isolation

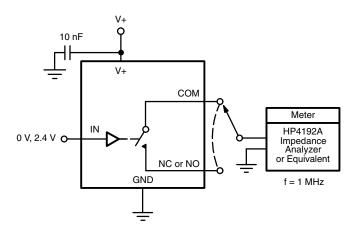


Figure 5. Channel Off/On Capacitance

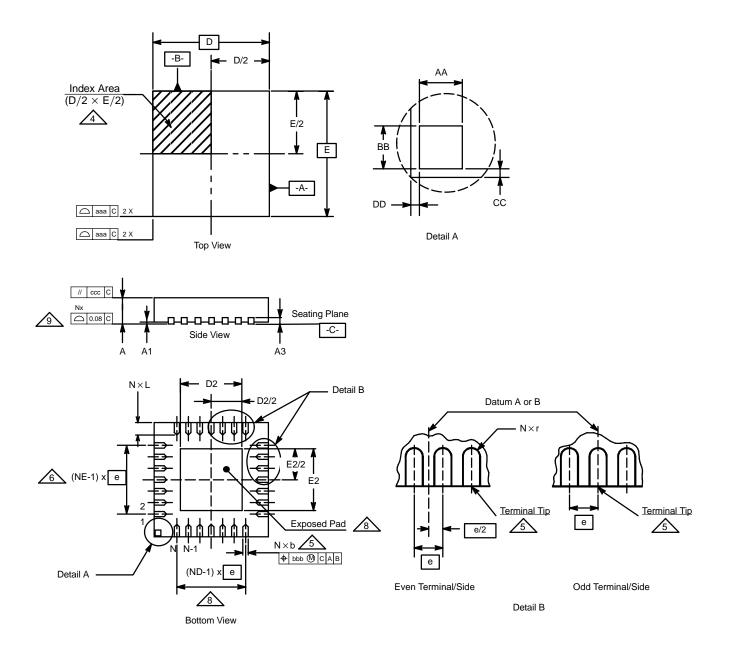
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?71971.

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Package Information Vishay Siliconix

QFN-16 (4×4 mm) JEDEC Part Number: MO-220





QFN-16 (4×4 mm)

JEDEC Part Number: MO-220

	MI	ILLIMETERS* INCHES		INCHES			
Dim	Min	Nom	Max	Min	Nom	Max	Notes
А	0.80	0.90	1.00	0.0315	0.0354	0.0394	
A1	0	0.02	0.05	0	0.0008	0.0020	
A3	-	0.20 Ref	-	-	0.0079	-	
AA	-	0.345	-	-	0.0136	-	
aaa	-	0.25	-	-	0.0098	-	
BB	-	0.345	-	-	0.0136	-	
b	0.23	0.30	0.38	0.0091	0.0118	0.0150	5
bbb	-	0.10	-	-	0.0039	-	
CC	-	0.18	-	-	0.0071	-	
CCC	-	0.10	-	-	0.0039	-	
D		4.00 BSC			0.1575 BSC		
D2	2.00	2.15	2.25	0.0787	0.0846	0.0886	
DD	-	0.18	-	-	0.0071	-	
Е	4.00 BSC			0.1575 BSC			
E2	2.00	2.15	2.25	0.0787	0.0846	0.0886	
е		0.65 BSC			0.0256 BSC		
L	0.45	0.55	0.65	0.0177	0.0217	0.0256	
Ν	16			16		3, 7	
ND	-	4	-	-	4	-	6
NE	-	4	-	-	4	-	6
r	b(min)/2	-	-	b(min)/2	-	-	

* Use millimeters as the primary measurement.

ECN: S-21437—Rev. A, 19-Aug-02 DWG: 5890

NOTES:

1. Dimensioning and tolerancing conform to ASME Y14.5M-1994.

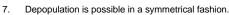
2. All dimensions are in millimeters. All angels are in degrees.

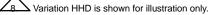
3. N is the total number of terminals.

4. The terminal #1 identifier and terminal numbering convention shall conform to JESD 95-1 SPP-012. Details of terminal #1 identifier are optional, but must be located within the zone indicated. The terminal #1 identifier may be either a molded or marked feature. The X and Y dimension will vary according to lead counts.

 $\sqrt{5.2}$ Dimension b applies to metallized terminal and is measured between 0.25 mm and 0.30 mm from the terminal tip.

 $\underline{/6.}$ ND and NE refer to the number of terminals on the D and E side respectively.

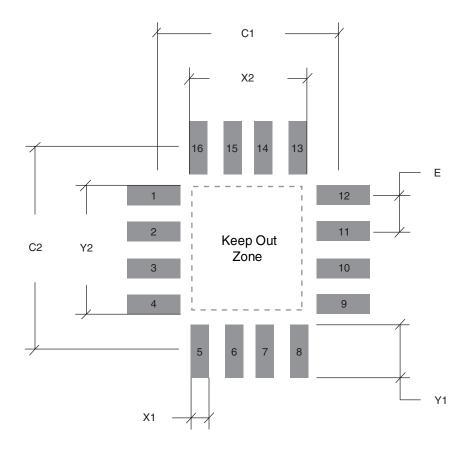




 $\sqrt{9.}$ Coplanarity applies to the exposed heat sink slug as well as the terminals.



RECOMMENDED MINIMUM PADS FOR QFN-16 (4 x 4 MM BODY)



	Inches	Millimeters
C1	0.142	3.60
C2	0.142	3.60
E	0.026	0.65
X1	0.014	0.35
X2	0.089	2.25
Y1	0.037	0.95
Y2	0.089	2.25

Note:

QFN-16 (4 x 4) has an exposed center pad that must not come into contact with any metalized structure on the PCB. This area is considered a Keep Out Zone.



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